

HD74LS166A

8-bit Shift Register

REJ03D0450-0300

Rev.3.00

Jul.15.2005

The inputs are buffered to lower the drive requirements to one series 74 or 74LS standard load, respectively. Input clamping diodes minimize switching transients and simplify system design. This parallel in or serial-in, serial-out shift register has a complexity of 77 equivalent gates on a monolithic chip. This device features gated clock inputs and an overriding clear input.

The parallel-in or serial-in modes are established by the shift / load input.

When high, this input enables the serial data input and couples the eight flip-flops for serial shifting with each clock pulse. When low, the parallel (broadside) data inputs are enabled and synchronous loading occurs on the next clock pulse, during parallel loading, serial data flow is inhibited.

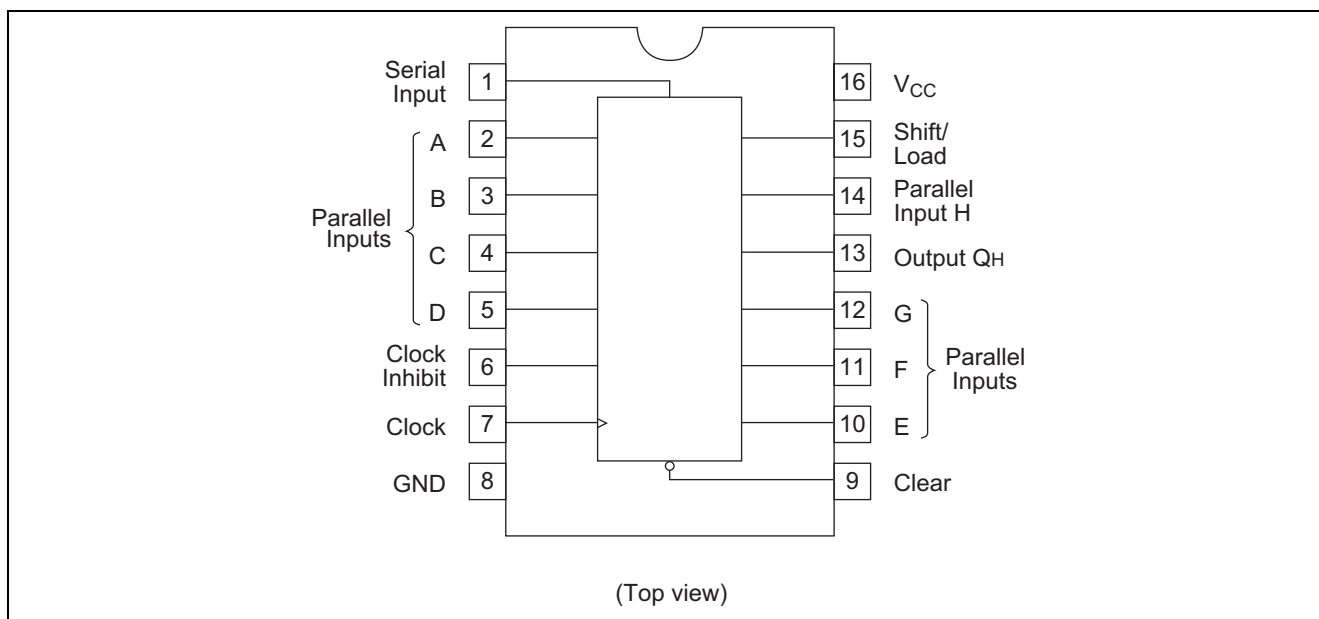
This, of course, allows the system clock to be free running and the register can be stopped on command with the other clock input. The clock-inhibit input should be changed to the high level only while the clock input is high. A buffered, direct clear input overrides all other inputs, including the clock, and sets all flip-flops to zero.

Features

- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS166AP	DILP-16 pin	PRDP0016AE-B (DP-16FV)	P	—

Pin Arrangement

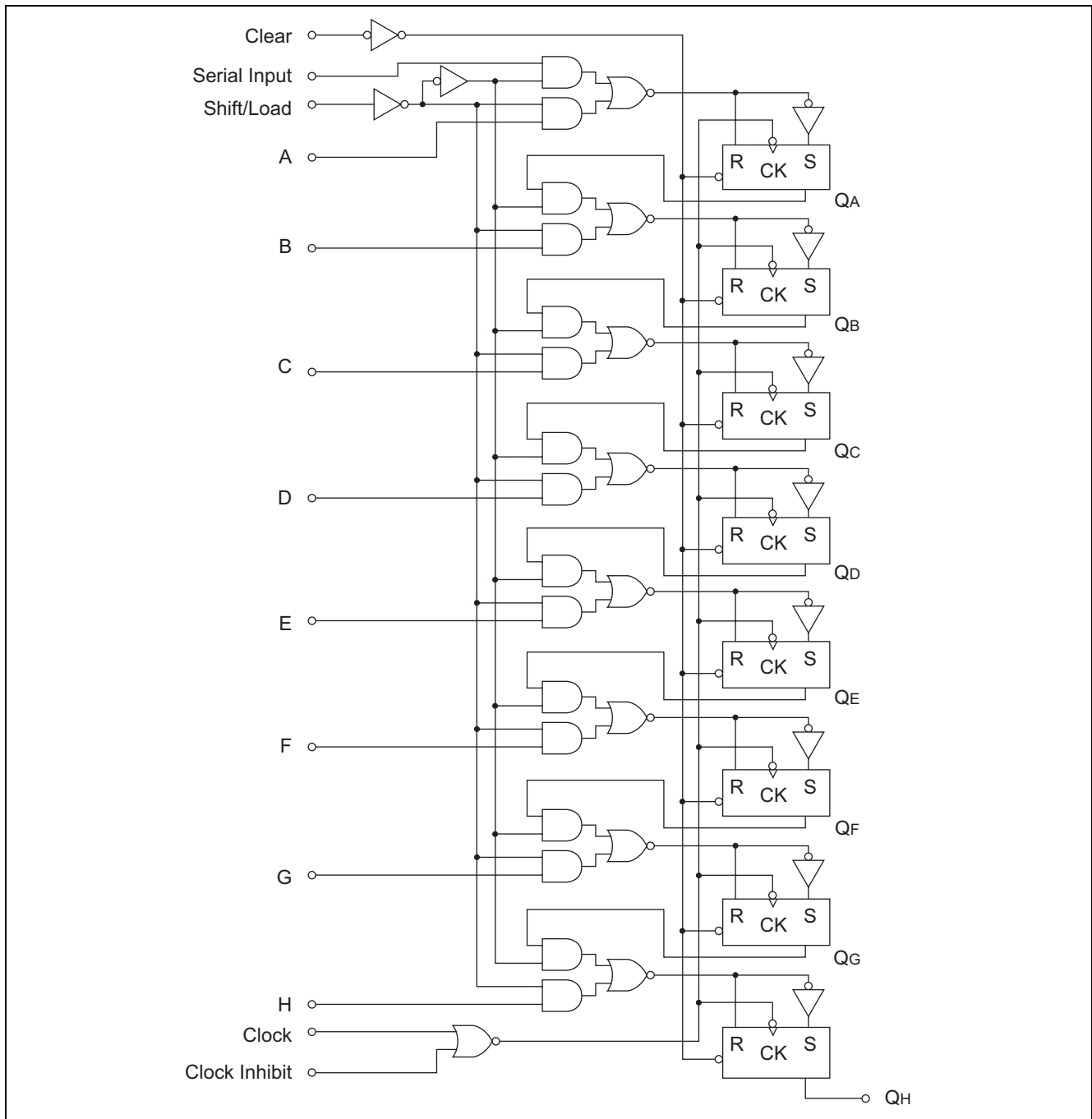


Function Table

Inputs					Parallel A...H	Internal outputs		Output Q _H
Clear	Shift Load	Clock Inhibit	Clock	Serial		Q _A	Q _B	
L	X	X	X	X	X	L	L	L
H	X	L	L	X	X	Q _{A0}	Q _{B0}	Q _{H0}
H	L	L	↑	X	a...h	a	b	h
H	H	L	↑	H	X	H	Q _{An}	Q _{Gn}
H	H	L	↑	L	X	L	Q _{An}	Q _{Gn}
H	X	H	↑	X	X	Q _{A0}	Q _{B0}	Q _{H0}

- Notes:
1. H; high level, L; low level, X; irrelevant
 2. ↑; transition from low to high level
 3. a to h; the level of steady-state input at inputs A to H respectively
 4. Q_{A0} to Q_{H0}; the level of Q_A to Q_H, respectively, before the indicated steady-state input conditions were established.
 5. Q_{An} to Q_{Gn}; the level of Q_A to Q_G, respectively, before the most recent ↑ transition of the clock.

Block Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V_{CC}	7	V
Input voltage	V_{IN}	7	V
Power dissipation	P_T	400	mW
Storage temperature	T_{stg}	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{CC}	4.75	5.00	5.25	V
Output current	I_{OH}	—	—	−400	μA
	I_{OL}	—	—	8	mA
Operating temperature	T_{opr}	−20	25	75	°C
Clock frequency	f_{clock}	0	—	25	MHz
Clock and clear pulse width	t_w	20	—	—	ns
Mode control setup time	t_{su}	30	—	—	ns
Data setup time	t_{su}	20	—	—	ns
Hold time	t_h	0	—	—	ns

Electrical Characteristics

(Ta = −20 to +75 °C)

Item	Symbol	min.	typ.*	max.	Unit	Condition
Input voltage	V_{IH}	2.0	—	—	V	
	V_{IL}	—	—	0.8	V	
Output voltage	V_{OH}	2.7	—	—	V	$V_{CC} = 4.75 \text{ V}$, $V_{IH} = 2 \text{ V}$, $V_{IL} = 0.8 \text{ V}$, $I_{OH} = -400 \mu A$
	V_{OL}	—	—	0.4	V	$I_{OL} = 4 \text{ mA}$
		—	—	0.5		$I_{OL} = 8 \text{ mA}$
Input current	I_{IH}	—	—	20	μA	$V_{CC} = 5.25 \text{ V}$, $V_I = 2.7 \text{ V}$
	I_{IL}	—	—	−0.4	mA	$V_{CC} = 5.25 \text{ V}$, $V_I = 0.4 \text{ V}$
	I_I	—	—	0.1	mA	$V_{CC} = 5.25 \text{ V}$, $V_I = 7 \text{ V}$
Short-circuit output current	I_{OS}	−20	—	−100	mA	$V_{CC} = 5.25 \text{ V}$
Supply current**	I_{CC}	—	20	32	mA	$V_{CC} = 5.25 \text{ V}$
Input clamp voltage	V_{IK}	—	—	−1.5	V	$V_{CC} = 4.75 \text{ V}$, $I_{IN} = -18 \text{ mA}$

Notes: * $V_{CC} = 5 \text{ V}$, Ta = 25°C

** With the outputs open, 4.5 V applied to the serial input and all other inputs except the clock grounded, I_{CC} is measured after a momentary ground, then 4.5 V, is applied to clock.

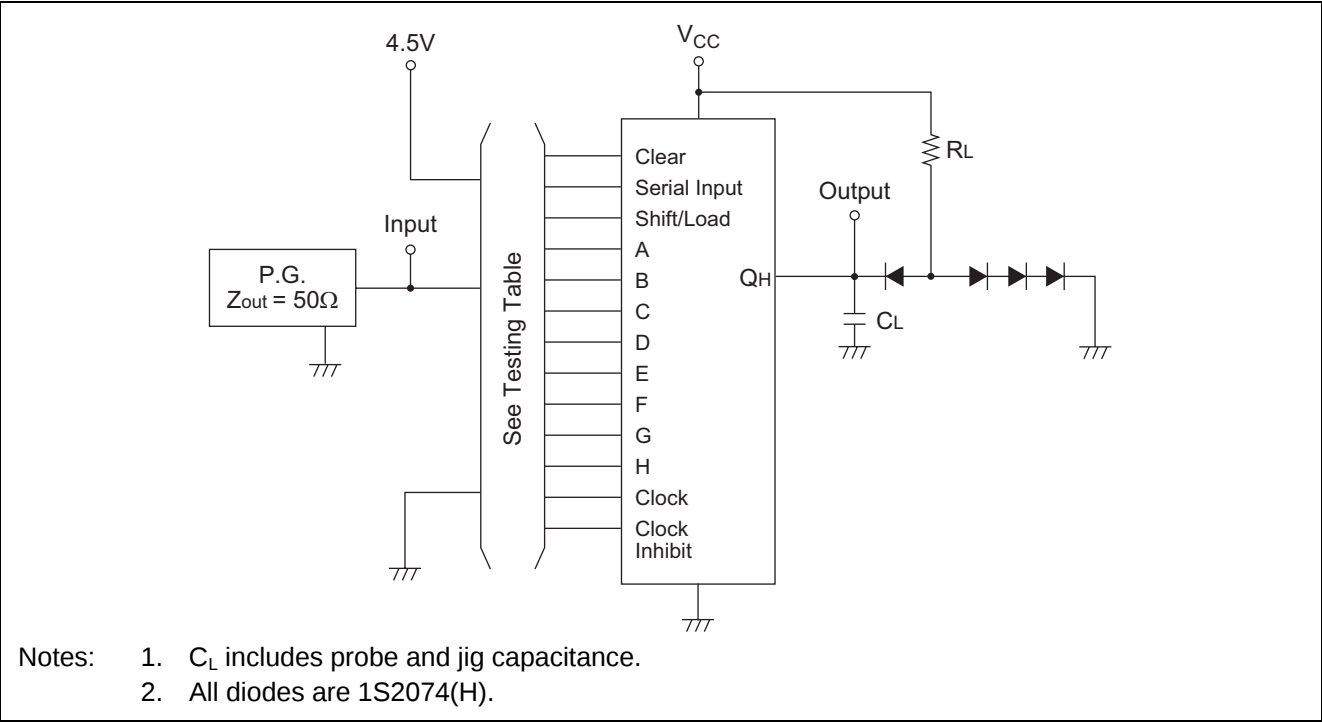
Switching Characteristics

(V_{CC} = 5 V, Ta = 25°C)

Item	Symbol	Inputs	min.	typ.	max.	Unit	Condition
Maximum clock frequency	f_{max}		25	35	—	MHz	$C_L = 15 \text{ pF}$, $R_L = 2 \text{ k}\Omega$
Propagation delay time	t_{PHL}	Clear	—	19	30	ns	
	t_{PHL}	Clock	7	14	25	ns	
	t_{PLH}		5	11	20	ns	

Testing Method

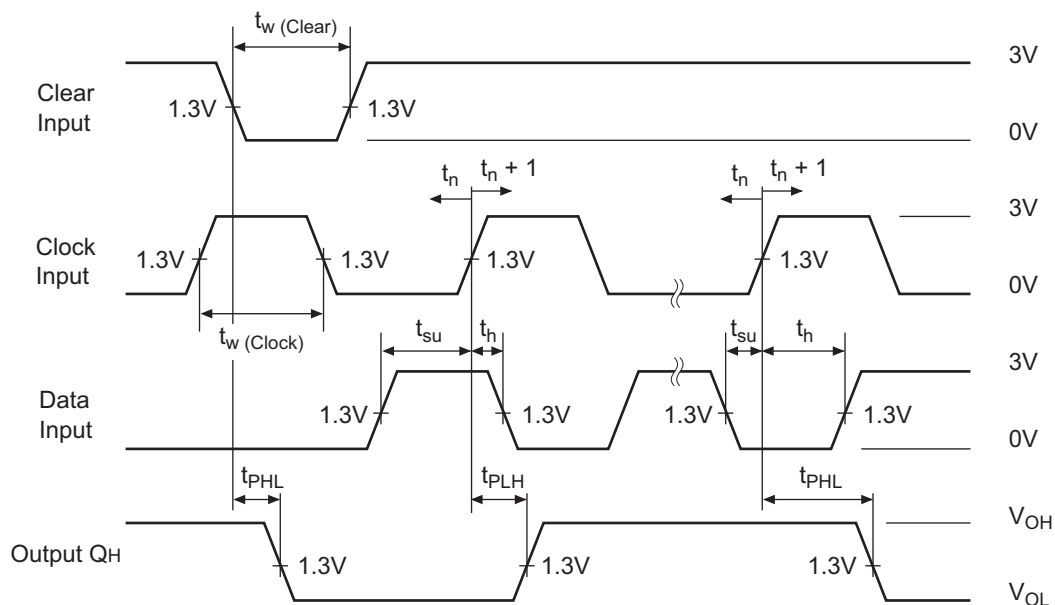
Test Circuit



Testing table

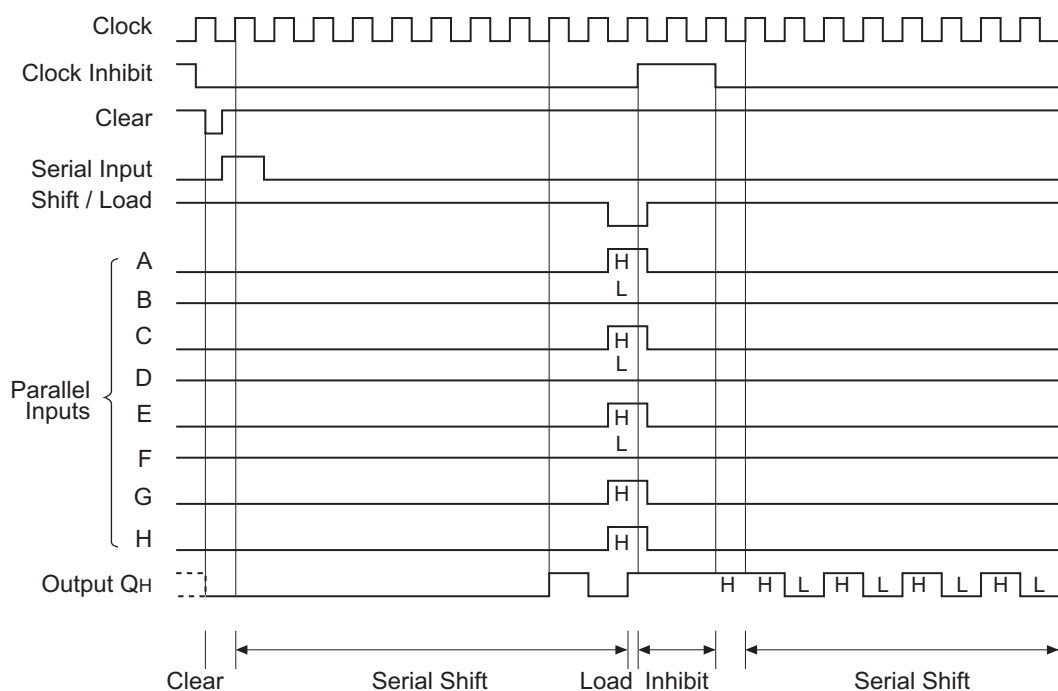
Data inputs	Shift / Load	Output	Bit time
Data H	0 V	Q_H	t_{n+1}
Serial-in	4.5 V	Q_H	t_{n+8}

Waveform

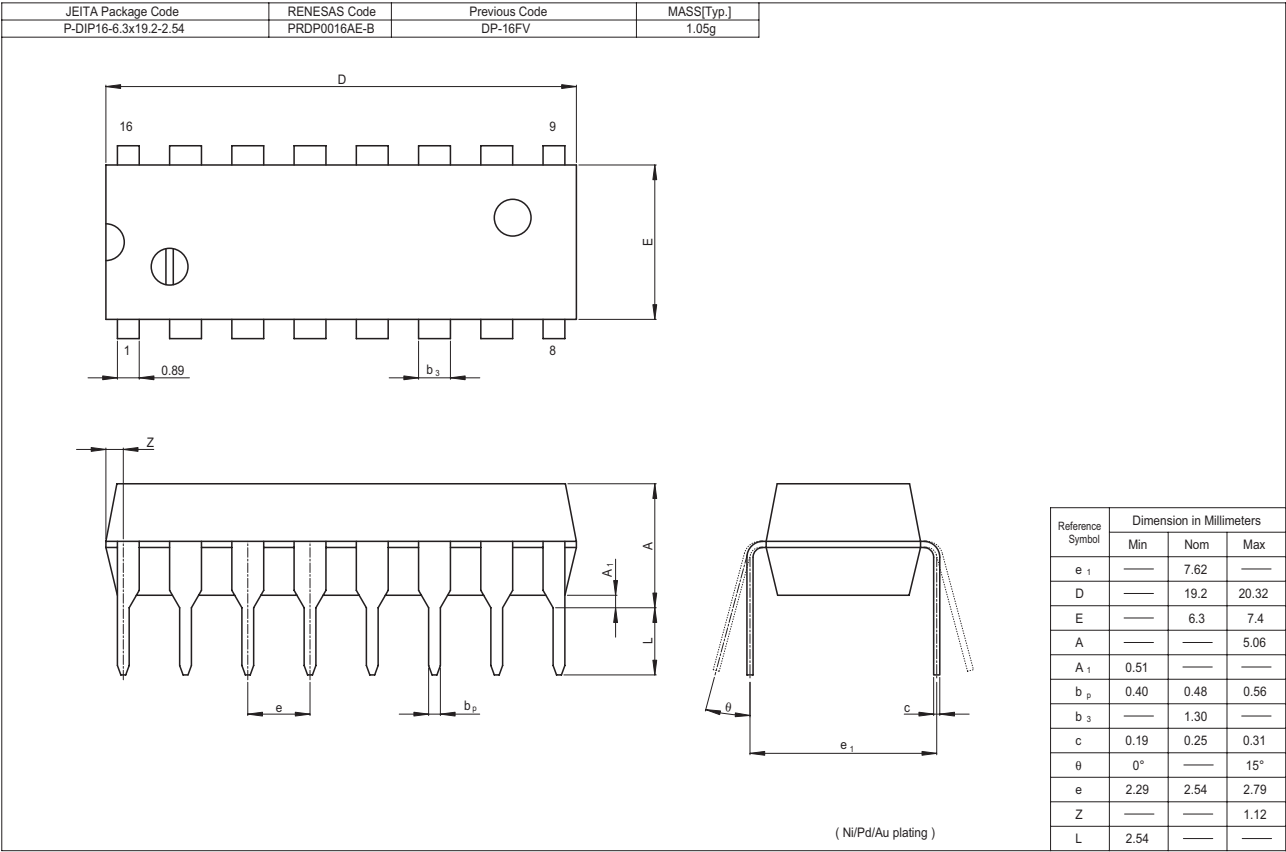


- Notes:
1. Input pulse; ≤ 15 ns, $t_{THL} \leq 6$ ns, PRR = 1 MHz, duty cycle 50%
 Clock input; $t_w \geq 20$ ns
 Clear input; $t_w \geq 20$ ns, $t_h = 10$ ns, when testing f_{max} , vary the clock PRR.
 2. Propagation delay time (t_{PLH} and t_{PHL}) are measured at t_{n+1} . Proper shifting of data is verified at t_{n+8} with a functional test.
 3. t_n ; bit time before clocking transition.
 t_{n+1} ; bit time after one clocking transition.
 t_{n+8} ; bit time after eight clocking transition.

Typical Clear, Shift, Load, Inhibit, and Shift Sequences



Package Dimensions



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Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A
Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology Hong Kong Ltd.

7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong
Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd.

10th Floor, No.99, Fushing North Road, Taipei, Taiwan
Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology (Shanghai) Co., Ltd.

Unit2607 Ruijing Building, No.205 Maoming Road (S), Shanghai 200020, China
Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

Renesas Technology Singapore Pte. Ltd.

1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632
Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd.

Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea
Tel: <82> 2-796-3115, Fax: <82> 2-796-2145

Renesas Technology Malaysia Sdn. Bhd.

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: <603> 7955-9390, Fax: <603> 7955-9510